Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	4	(("5451548") or ("5474851") or ("5897812") or ("4377613")).PN.	USPAT	OR	OFF	2006/09/11 16:41
S2	237	427/255.23.ccls.	US-PGPUB; USPAT; DERWENT; IBM_TDB	OR	ON	2006/09/11 16:32
S3	714	427/255.28.ccls.	US-PGPUB; USPAT; DERWENT; IBM_TDB	OR	ON	2006/09/11 16:32
S4	2496	427/248.1.ccls.	US-PGPUB; USPAT; DERWENT; IBM_TDB	OR	ON	2006/09/11 16:40
S5	8	remington-michael-p\$.in.	US-PGPUB; USPAT; DERWENT; IBM_TDB	OR	ON	2006/09/11 16:33
S6	22	strickler-david-a.in.	US-PGPUB; USPAT; DERWENT; IBM_TDB	OR	ON	2006/09/11 16:33
S7	16	varanasi-srikanth.in.	US-PGPUB; USPAT; DERWENT; IBM_TDB	OR	ON	2006/09/11 16:33
S8	0	S2 and (gallium oxide)	US-PGPUB; USPAT; DERWENT; IBM_TDB	ADJ	ON	2006/09/11 16:40
S9	4	S3 and (gallium oxide)	US-PGPUB; USPAT; DERWENT; IBM_TDB	ADJ	ON	2006/09/11 16:41
S10	8	S4 and (gallium oxide)	US-PGPUB; USPAT; DERWENT; IBM_TDB	ADJ	ON	2006/09/11 16:41
S11	26	(chemical vapor deposition) same (gallium oxide)	US-PGPUB; USPAT; DERWENT; IBM_TDB	ADJ	ON	2006/09/12 07:48
S12	2769	(gallium oxide)	US-PGPUB; USPAT; DERWENT; IBM_TDB	ADJ	ON	2006/09/11 16:45

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S13	- 58	(chemical vapor deposit\$3 or \$cvd or vapor deposit\$3) same (gallium oxide)	US-PGPUB; USPAT; DERWENT; IBM_TDB	ADJ	ON	2006/09/11 16:58
S14	1	S13 and (ethyl acetate or isobutyl acetate or n-butyl acetate or tert-butyl acetate or ethyl formate)	US-PGPUB; USPAT; DERWENT; IBM_TDB	ADJ	ON	2006/09/11 16:47
S15	98	(ethyl acetate or isobutyl acetate or n-butyl acetate or t-butyl acetate or tert-butyl acetate or ethyl formate) and (gallium oxide)	US-PGPUB; USPAT; DERWENT; IBM_TDB	ADJ	ON	2006/09/11 16:47
S16	98	(ethyl acetate or isobutyl acetate or n-butyl acetate or t-butyl acetate or tert-butyl acetate or ethyl formate) and (gallium oxide)	US-PGPUB; USPAT; DERWENT; IBM_TDB	ADJ	ON	2006/09/12 07:52
S17	8	S16 and (\$2cvd or vapor deposition)	US-PGPUB; USPAT; DERWENT; IBM_TDB	ADJ	ON	2006/09/11 17:35
S18	935	(chemical vapor deposit\$3 or \$2cvd or vapor deposit\$3) same (gallium with oxide)	US-PGPUB; USPAT; DERWENT; IBM_TDB	ADJ	ON	2006/09/11 17:37
S20	74	(chemical vapor deposit\$3 or \$2cvd or vapor deposit\$3) same (gallium with oxide) and (ethyl acetate or isobutyl acetate or n-butyl acetate or t-butyl acetate or tert-butyl acetate or ethyl formate)	US-PGPUB; USPAT; DERWENT; IBM_TDB	ADJ	ON	2006/09/11 17:42
S21	6	("4187336" "4331737" "4371587" "4595634").PN, OR ("5474851").URPN.	US-PGPUB; USPAT; USOCR	OR 🚽	ON	2006/09/11 17:38
S22	74	(chemical vapor deposit\$3 or \$2cvd or vapor deposit\$3) same ((gallium with oxide) or ("ga.sub.2o.sub.3")) and (ethyl acetate or isobutyl' acetate or n-butyl acetate or t-butyl acetate or tert-butyl acetate or ethyl formate)	US-PGPUB; USPAT; DERWENT; IBM_TDB	ADJ	ON	2006/09/11 17:44
S23	80	(chemical vapor deposit\$3 or \$2cvd or vapor deposit\$3) same ((gallium with oxide) or ("ga.sub.2o.sub.3")) and (ester)	US-PGPUB; USPAT; DERWENT; IBM_TDB	ADJ	ON	2006/09/11 17:44
S24	54	S23 not S22	US-PGPUB; USPAT; DERWENT; IBM_TDB	ADJ	ON .	2006/09/11 17:44

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S25	2	("4,187,336").PN.	US-PGPUB; USPAT; DERWENT; IBM_TDB	OR	OFF	2006/09/12 07:07
S26	46	gordon-roy-g.in.	US-PGPUB; USPAT; DERWENT;	OR	ON	2006/09/12 07:22
			IBM_TDB		i i	
S27	18	S26 and gallium	US-PGPUB; USPAT; DERWENT; IBM_TDB	OR	ON	2006/09/12 07:26
S29	71	(((gallium with oxide) ("ga.sub.2o. sub.3") gallia) with (film layer)) same (\$2cvd (chemical adj vapor adj deposit\$2)) same (glass with (substrate ribbon plate wafer))	US-PGPUB; USPAT; DERWENT; IBM_TDB	OR	ON	2006/09/12 07:49
S31	12557	(gallium with oxide)	US-PGPUB; USPAT; DERWENT; IBM_TDB	OR	ON	2006/09/12 07:33
S32	17	S31 with (film layer) same (\$2cvd (chemical adj vapor adj deposit\$2))	US-PGPUB; USPAT;	OR	ON	2006/09/12 07:48
		same (glass with (substrate ribbon plate wafer))	DERWENT; IBM_TDB			
S33	197534	(aluminum with oxide)	US-PGPUB; USPAT; DERWENT; IBM_TDB	OR	ON	2006/09/12 07:34
S34	310	S33 with (film layer) same (\$2cvd (chemical adj vapor adj deposit\$2)) same (glass with (substrate ribbon plate wafer))	US-PGPUB; USPAT; DERWENT; IBM_TDB	OR	ON	2006/09/12 07:44
S35	1	S34 and (aluminum adj trichloride)	US-PGPUB; USPAT; DERWENT; IBM_TDB	OR	ON	2006/09/12 07:35
S37	17	S31 with (film layer coating) same (\$2cvd (chemical adj vapor adj deposit\$2)) same (glass with (substrate ribbon plate wafer))	US-PGPUB; USPAT; DERWENT; IBM_TDB	OR	ON	2006/09/12 07:48
S38	4	(chemical vapor deposition) same (gallium oxide)	EPO; JPO; DERWENT	ADJ	ON	2006/09/12 07:49
S39	3	(((gallium with oxide) ("ga.sub.2o. sub.3") gallia) with (film layer)) same (\$2cvd (chemical adj vapor adj deposit\$2)) same (glass with (substrate ribbon plate wafer))	USOCR; EPO; JPO	OR	ON	2006/09/12 07:50

S40	5	(ethyl acetate or isobutyl acetate or n-butyl acetate or t-butyl acetate or tert-butyl acetate or ethyl formate) and (gallium chloride) and (gallium oxide)	US-PGPUB; USPAT; DERWENT; IBM_TDB	ADJ	ON	2006/09/12 07:53
S41	12	("5389401").URPN.	USPAT	OR	ON	2006/09/12 08:28
S42	6	("4187336" "4331737" "4371587" "4595634").PN. OR ("5474851").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/09/12 08:35
S44	. 12	("4187336" "4331737" "4371587" "4595634").PN. OR	US-PGPUB; USPAT;	OR	ON	2006/09/12 08:35
- 3	*	("5474851").URPN.	USOCR; EPO; JPO;			
·			DERWENT; IBM_TDB	*		